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| SANYO | No.686I | <h1 style="margin: 0;">2SB824/2SD1060</h1> <p style="margin: 0;">PNP/NPN Epitaxial Planar Silicon Transistors</p> <p style="margin: 0;">50V/5A Switching Applications</p> |
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APPLICATIONS

- Suitable for relay drivers, high-speed inverters, converters, and other general large-current switching

FEATURES

- Low collector-emitter saturation voltage: $V_{CE(sat)} = (-)0.4V \text{ max} / I_C = (-)3A, I_B = (-)0.3A$

Values for 2SB824 shown in ()

ABSOLUTE MAXIMUM RATINGS/Ta=25°C

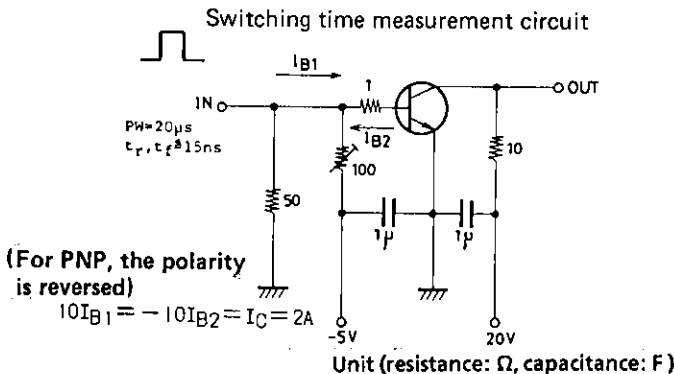
| | | | unit |
|---------------------------------|-----------|-----------------------|------|
| Collector-to-base voltage | V_{CBO} | (-)60 | V |
| Collector-to-emitter voltage | V_{CEO} | (-)50 | V |
| Emitter-to-base voltage | V_{EBO} | (-)6 | V |
| Collector current | I_C | (-)5 | A |
| Collector Current (Pulse) | I_{CP} | (-)9 | A |
| Allowable collector dissipation | P_C | $T_c = 25^\circ C$ 30 | W |
| Junction temperature | T_j | 150 | °C |
| Storage ambient temperature | T_{stg} | -55~+150 | °C |

ELECTRICAL CHARACTERISTICS/Ta=25°C

| | | | min | typ | max | unit |
|--------------------------------------|---------------|---------------------------------|----------|-------|--------|------|
| Collector cut-off current | I_{CBO} | $V_{CB} = (-)40V, I_E = 0$ | | | (-)0.1 | mA |
| Emitter cut-off current | I_{EBO} | $V_{EB} = (-)4V, I_C = 0$ | | | (-)0.1 | mA |
| DC current gain | $h_{FE}(1)$ | $V_{CE} = (-)2V, I_C = (-)1A$ | 70* | | 280* | |
| | $h_{FE}(2)$ | $V_{CE} = (-)2V, I_C = (-)3A$ | 30 | | | |
| Gain bandwidth product | f_T | $V_{CE} = (-)5V, I_C = (-)1A$ | | 30 | | MHz |
| Output capacitance | C_{ob} | $V_{CB} = (-)10V, f = 1MHz$ | | 100 | | pF |
| | | | | (160) | | pF |
| Collector-emitter saturation voltage | $V_{CE(sat)}$ | $I_C = (-)3A, I_B = (-)0.3A$ | | | (-)0.4 | V |
| Collector-base breakdown voltage | $V_{(BR)CBO}$ | $I_C = (-)1mA, I_E = 0$ | (-)60 | | | V |
| Collector-emitter breakdown voltage | $V_{(BR)CEO}$ | $I_C = (-)1mA, R_{BE} = \infty$ | (-)50 | | | V |
| Emitter-base breakdown voltage | $V_{(BR)EBO}$ | $I_E = (-)1mA, I_C = 0$ | (-)6 | | | V |
| Turn-on time | t_{on} | at the appointed circuit | | 0.1 | | μs |
| Storage time | t_{stg} | at the appointed circuit | (0.7)1.4 | | | μs |
| Fall time | t_f | at the appointed circuit | | 0.2 | | μs |

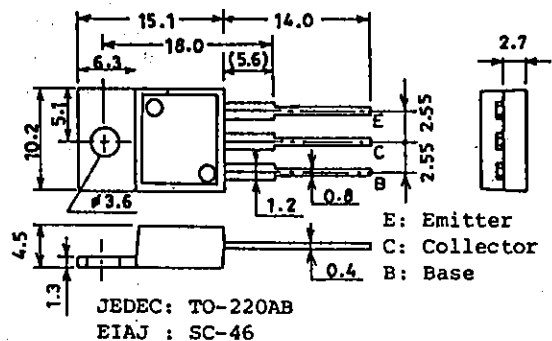
* 2SB824 and 2SD1060 are graded as follows by h_{FE} at 1A:

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|----|---|-----|-----|---|-----|-----|---|-----|
| 70 | Q | 140 | 100 | R | 200 | 140 | S | 280 |
|----|---|-----|-----|---|-----|-----|---|-----|

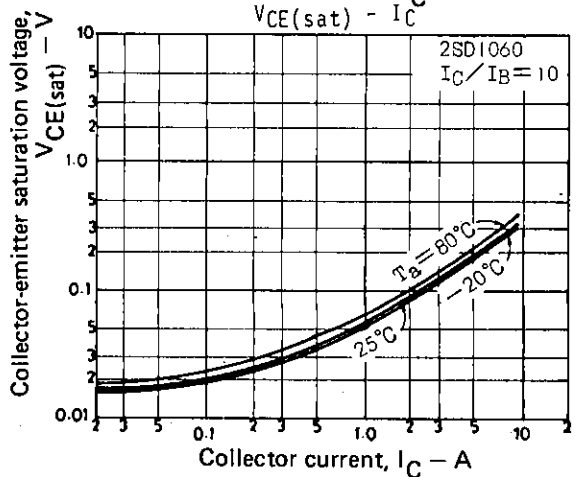
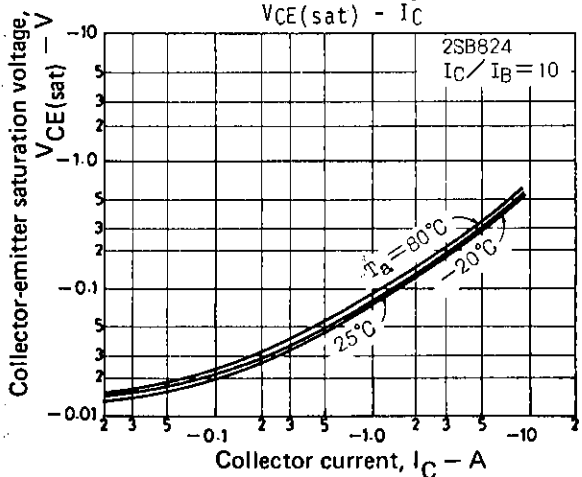
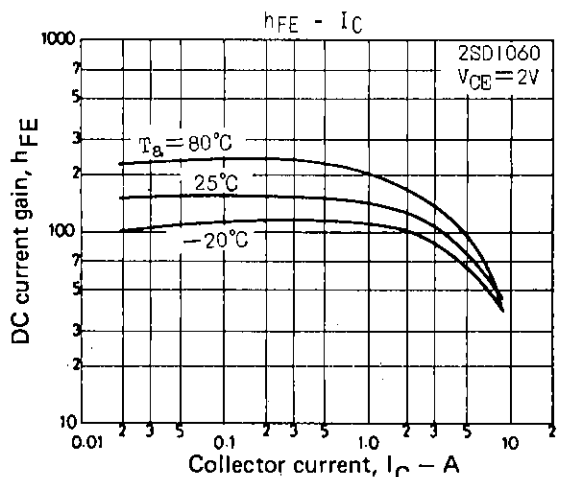
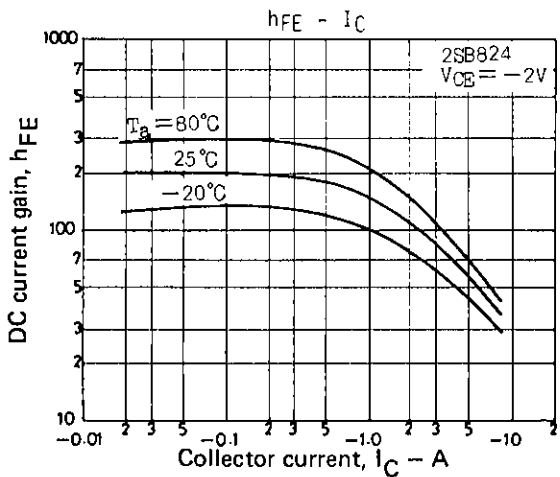
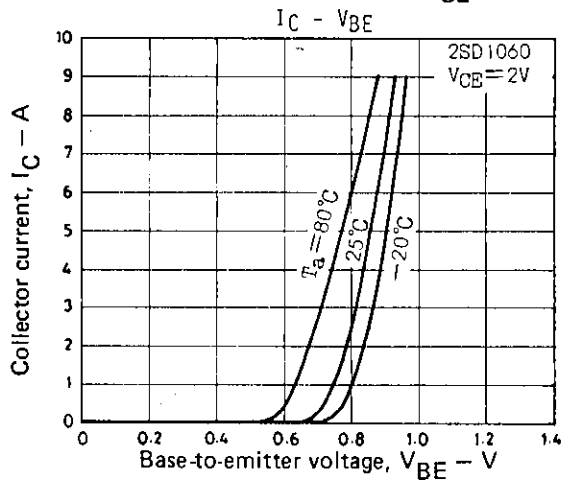
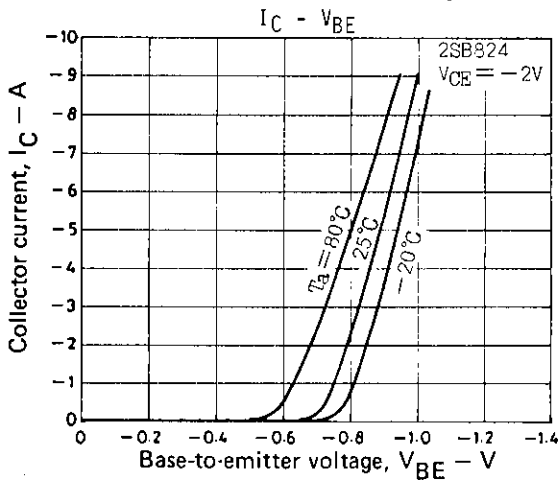
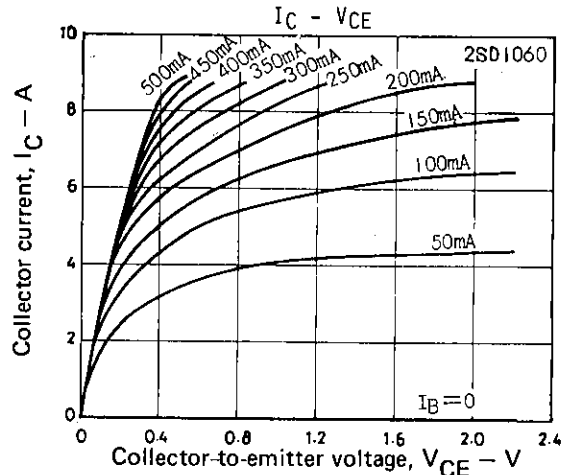
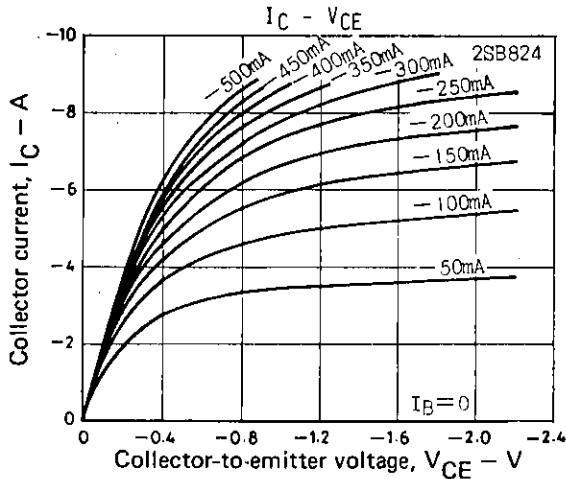


Package Dimensions 2010B

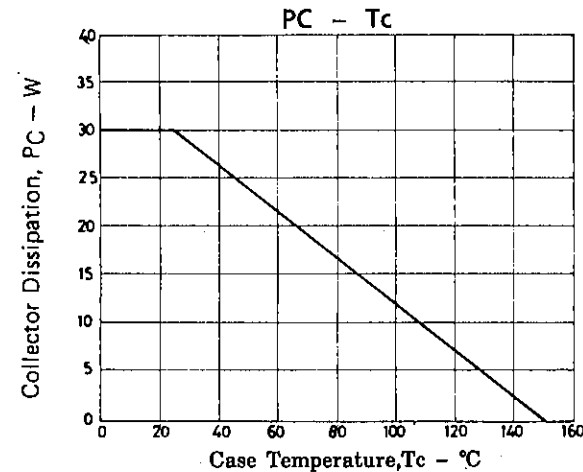
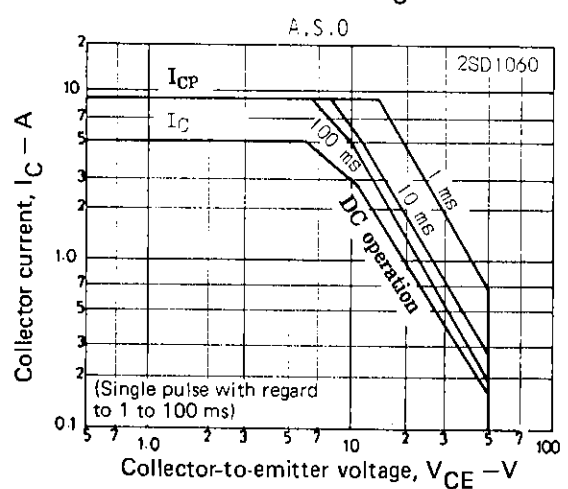
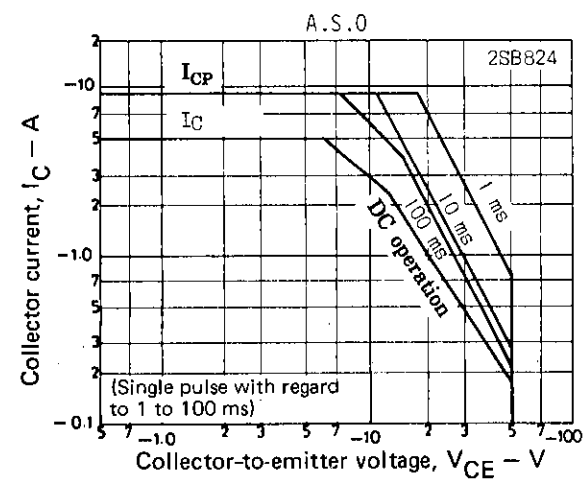
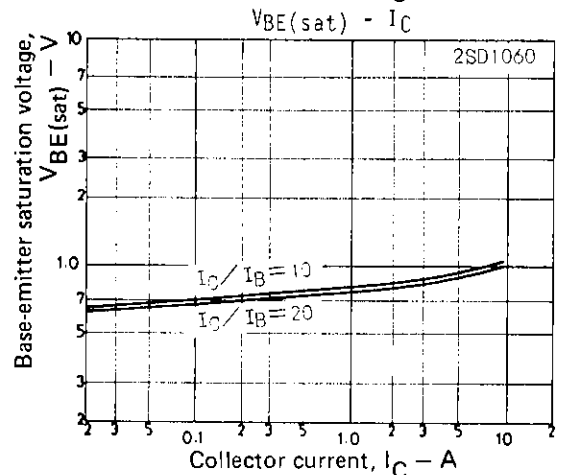
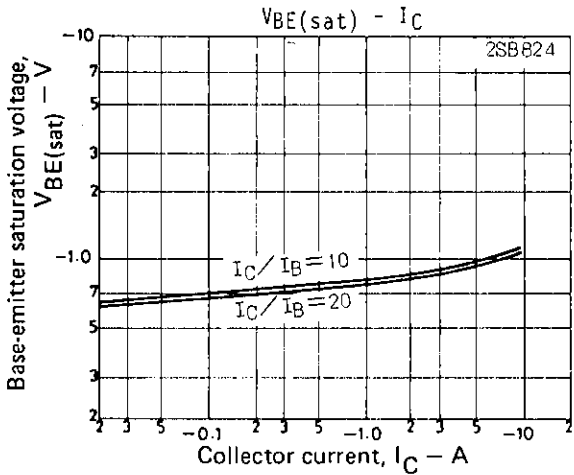
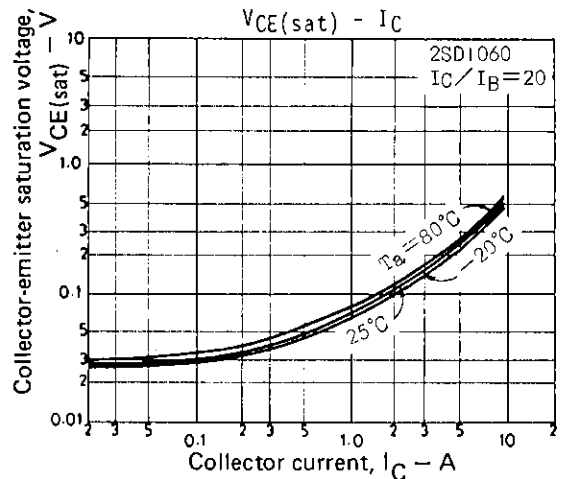
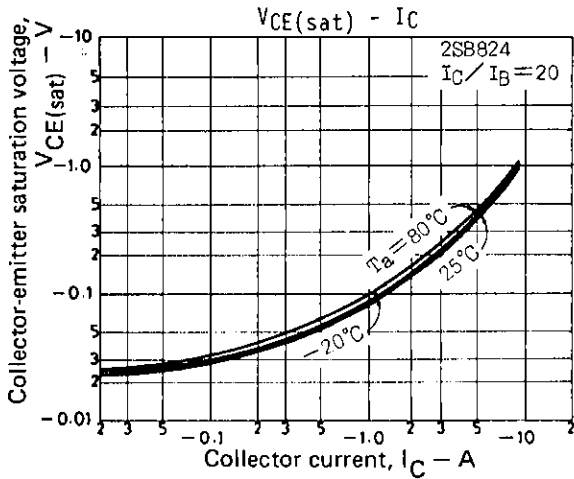
(unit: mm)



2SB824/2SD1060



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